

SANYO Semiconductors DATA SHEET



Monolithic Linear IC - High-Performance Dual Comparator

Overview

The LA6393JM is a high-performance dual comparator that is capable of operating from a single power supply over a wide range of 2V to 36V. Because of its excellent input characteristics and low power, it can be very conveniently applied to multi-signal parallel comparator circuits that require high-density assembly.

Functions

- High-performance dual operational amplifier
- Wide supply voltage range (Single supply : 2.0 to 36.0V, dual supplies : ±1.0 to 18.0V).
- Wide common-mode input voltage range (0 to $V_{CC} 1.8V$).
- Open collector output enabling wired OR.
- Small current drain (0.6mA) and low power.
- Mini flat package enabling compactness of sets.

Specifications

Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		36	V
Differential input voltage	V _{ID}		36	V
Maximum input voltage	V _{IN} max		-0.3 to +36	V
Allowable power dissipation	Pd max	Ta≤25°C	300	mW
Operating temperature	Topr		-40 to +85	°C
Storage temperature	Tstg		-55 to +150	°C

Recommended Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Linit
			Min	typ	Max	Unit
Supply voltage	Vcc		2		24	V

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Electrical Characteristics at $Ta = 25^{\circ}C$, $V_{CC} = 5V$

Parameter	Symbol	Conditions	Test	Ratings			1.114
			Circuit	min	typ	max	Unit
Input offset voltage	VIO		1		±2	±7	mV
Input offset current	IIO		2		±5	±50	nA
Input bias current	۱ _B		3		45	250	nA
Common-mode input voltage range	VICM			0		V _{CC} -1.8	V
Current drain	ICC	RL = ∞	4		0.5	1.2	mA
Voltage gain	VG	$R_{L} = 15k\Omega$	5		200		V/mV
Response time	RT	$V_{RL} = 5V, R_L = 5.1k\Omega$	6		1.3		μs
Output sink current	ISINK	$V_{IN}^{-} = 0.5V, V_{IN}^{+} = 0V, V_{O} \le 1.5V$	7	6	16		mA
Output saturation voltage	VOL	$V_{IN}^{-} = 0.5V, V_{IN}^{+} = 0V, I_{SINK} \le 3mA$	8		0.2	0.4	V
Output leakage current	ILEAK	$V_{IN}^{-} = 0V, V_{IN}^{+} = 0.5V, V_{O} = 5V$	9		0.1		nA

Package Dimensions

unit : mm 3032D





Pin Assignment





Equivalent Circuit



Test Circuits

1. Input offset voltage V_{IO}







MSP05204

2. Input offset current IIO



Input bias current $I_B(+)$



MSP05205

4. Current drain I_{CC}

5. Voltage gain VG





6. Response time RT





7. Output sink current ISINK





8. Output saturation voltage VOL

9. Output leakage current $\ I_{LEAK}$



Application Circuit Examples

Voltage comparator (with hysteresis)



Square wave generator



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